

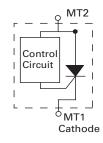
#### RoHS **PLED Series**



#### **Agency Approvals**

Agency	Agency File Number
<i>.</i> <b>9</b> <i>1</i>	(PENDING) E133083

#### **Schematic Symbol**



## Description

PLED Series open LED protectors provide a switching electronic shunt path when an LED in an LED string fails as an open circuit. This ensures that the remaining string of LEDs will continue to function if a single LED does not.

PLED Series devices were designed to enable higher reliability in outdoor LED lighting applications such as street lighting, outdoor signage, aircraft runway lighting, roadside warning lights and other applictions.

Compatible with one, two and three watt LEDs that have a nominal 3V forward characteristic, PLED Series devices are available in two surface mount packages, the DO-214 and the Quad Flat Pak No-lead (QFN). The QFN's low profile, chip scale package (CSP) is ideal for dense board applications.

### **Features & Benefits**

- · Fast switching
- Automatically resets after power cycle
- Available in low profile, small footprint QFN and Standard DO214AA packages
- Compatible with industrial lighting environments

*.R* 

- Compatible with PWM frequencies up to 30 kHz
- RoHS compliant and halogen-free

#### Electrical Characteristics (All parameters are measured at T=25°C unless otherwise noted)

Part Number	Marking	V <sub>₿R</sub> breakdown Volts		V <sub>DRM</sub> breakdown Volts	I <sub>H</sub> mAmps	I <sub>s</sub> mAmps	I <sub>τ</sub> @V <sub>τ</sub> Amps	V <sub>T</sub> @ I <sub>T</sub> = 1 Amp Volts	Critical rate of rise dV/dt Volts				
		Min	Max	Min	Min	Max	Max	Max	Max				
PLED6Q12	PL6	0	10	0									
PLED6S	PL6	6	16	6	5 100			10	050\//				
PLED9Q12	PL9	9	18	9									
PLED9S	PL9					100	10						
PLED13Q12	PL13	13	10	10	10	10	00	10	5	100	1.0	1.2	250V/µs
PLED13S	PL13		26	13									
PLED18Q12	PL18	10	33										
PLED18S	PL18	18		18									

©2011 Littelfuse, Inc.



hermal Cor	nsiderations				
Pack	kage	Symbol	Parameter	Value	Unit
QFN 3x3		Tj	Operating Junction Temperature Range	-40 to +150	°C
	DO-214	Τ <sub>s</sub>	Storage Temperature Range	-65 to +150	°C
		R <sub>eja</sub>	Thermal Resistance: Junction to Ambient	DO-214: 90 <sup>1</sup> DO-214: 40 <sup>2</sup> QFN: 120 <sup>1</sup> QFN: 60 <sup>3</sup>	°C/W

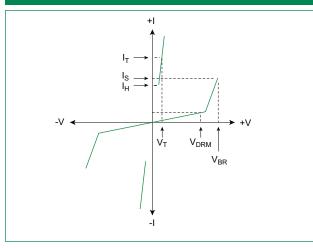
Notes:

1) Standard FR-4 PCB with Copper Pads (Recommended Size) 2) Aluminum PCB Thickness: 1.6mm Grade: 1-2 W/mK Thermal Conductivity Trace thickness: 2 oz Insulation layer thickness: 215 um Solder Pad Dimensions: 2.0mm x 2.8mm (Recommended Size) 3) Aluminum PCB Thickness: 1.6mm Grade: 1-2 W/mK Thermal Conductivity Trace thickness: 2 oz

Insulation layer thickness: 60 um

Solder Pad Dimensions: 1.27mm x 2.54mm (Recommended Size)

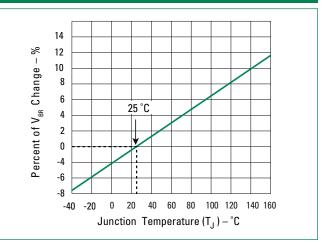
### **V-I Characteristics**



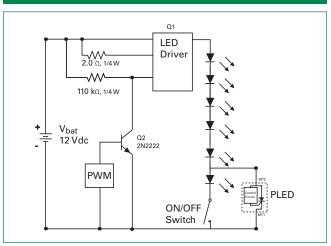
Normalized DC Holding Current vs. Case Temperature

#### 2.0 1.8 ົວ R atio of $\frac{1}{H}(T_c = 25^\circ)$ 1.6 .\_<del>\_</del> 1.4 25 °C 1.2 1.0 0.8 0.6 0.4 20 40 60 80 100 120 140 160 0 -40 -20 Case Temperature (T<sub>C</sub>) – $^{\circ}$ C

## V<sub>BR</sub> vs. Junction Temperature



## **LED Interference Test Circuit**

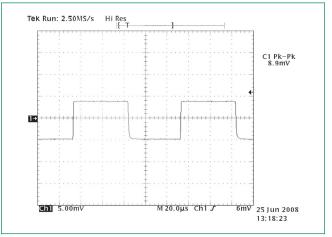


©2011 Littelfuse, Inc.

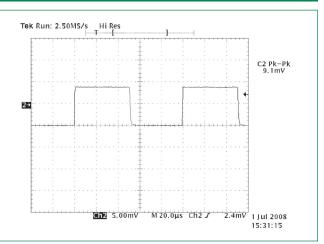
2 Revision: February 08, 2011

Specifications are subject to change without notice.

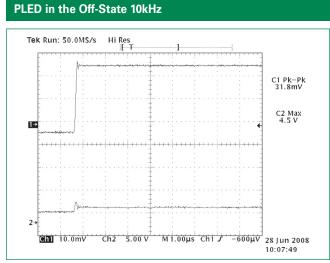
## 6 LEDs in Series 50% Duty Cycle 10kHz



### 5 LEDs and 1 PLED in Series 50% Duty Cycle 10kHz

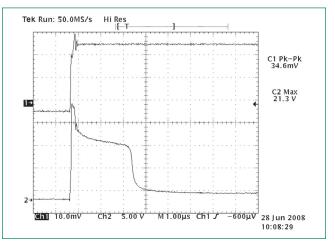


Note: These two graphs show the current magnitude through the LED string with and without the PLED included. There is no noticeable effect on the LED current magnitude when the PLED is included in the circuit as compared to the LED current magnitude when the PLED is not in the circuit. (The conversion factor for the test measurement in the graphs above is 10mA/mV for the Pearson coil measurement, therefore, the current magnitude in the first figure is 10mA\*8.9 = 89mA, while the second figure is 91mA.)



Channel 1: current through LEDs (318 mA) Channel 2: voltage across PLED device (4.5 V)

#### PLED device zeners and then turns fully on 10kHz



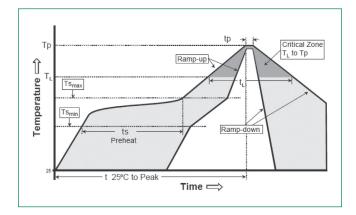
Channel 1: current through LEDs (346 mA) and PLED device once it is fully turned on 2.5 µsec later Channel 2: voltage across PLED device (21.3 V before PLED crowbars with 2 V drop)

## **Soldering Parameters**

Reflow Co	ndition	Pb – Free assembly	
	-Temperature Min (T <sub>s(min)</sub> )	150°C	
Pre Heat	-Temperature Max (T <sub>s(max)</sub> )	200°C	
	-Time (min to max) (t <sub>s</sub> )	60 – 180 secs	
Average ra (T <sub>L</sub> ) to pea	amp up rate (Liquidus Temp k	3°C/second max	
T <sub>S(max)</sub> to T <sub>L</sub>	- Ramp-up Rate	3°C/second max	
Reflow	-Temperature (T <sub>L</sub> ) (Liquidus)	217°C	
nellow	-Temperature (t <sub>L</sub> )	60 – 150 seconds	
PeakTemp	erature (T <sub>P</sub> )	260 <sup>+0/-5</sup> °C	
Time with Temperatu	in 5°C of actual peak ıre (t <sub>p</sub> )	30 seconds	
Ramp-dov	vn Rate	6°C/second max	
Time 25°C	to peakTemperature (T <sub>P</sub> )	8 minutes max	
Do not exc	ceed	260°C	

## **Physical Specifications**

Terminal Material	Copper Alloy	
Terminal Finish	100% Matte Tin Plated	
Body Material	UL recognized epoxy meeting flammability classification 94V-0	

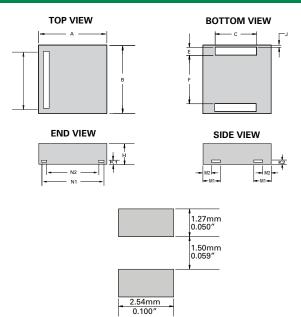


## **Environmental Specifications**

High Temperature Voltage Blocking	MIL-STD-750: Method 1040, Condition A 80% min V <sub>DRM</sub> (VAC-peak), 150°C, 504 hours
Temperature Cycling	MIL-STD-750: Method 1051 -65°C to 150°C, 15-minute dwell, 100 cycles
Biased Temperature & Humidity	EIA/JEDEC: JESD22-A101 52VDC, 85°C, 85%RH, 1008 hours
High Temperature Storage	MIL-STD-750: Method 1031 150°C, 1008 hours
Low Temperature Storage	-65°C, 1008 hours
Thermal Shock	MIL-STD-750: Method 1056 0°C to 100°C, 5-minute dwell, 10-second transfer, 10 cycles
Resistance to Solder Heat	MIL-STD-750: Method 2031 260°C, 10 seconds

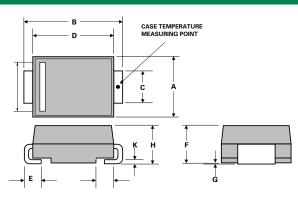


Dimensions - QFN (3x3) Package

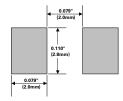


Dimensions	Min	Тур	Max	Min	Тур	Max
А	0.114	0.118	0.122	2.900	3.000	3.100
В	0.114	0.118	0.122	2.900	3.000	3.100
С	0.075	0.079	0.083	1.900	2.000	2.100
E	0.011	0.015	0.019	0.285	0.385	0.485
F	0.076	0.080	0.084	1.930	2.030	2.130
Н	0.035	0.039	0.043	0.900	1.000	1.100
J	0.000	0.004	0.008	0.000	0.100	0.200
K1	0.004	0.008	0.012	0.100	0.200	0.300
К2	0.004	0.008	0.012	0.100	0.200	0.300
M1	0.056	0.060	0.064	1.143	1.530	1.630
M2	0.038	0.042	0.046	0.970	1.070	1.170
N1	0.096	0.100	0.104	2.440	2.540	2.640
N2	0.082	0.086	0.090	2.080	2.180	2.280

### **Dimensions - DO-214 AA Package**



Recommended solder pad layout (Reference Only)



Recommended solder pad layout (Reference Only)

Dimensions	Inc	hes	Millimeters		
DIMENSIONS	Min	Max	Min	Max	
А	0.130	0.156	3.30	3.95	
В	0.201	0.220	5.10	5.60	
С	0.077	0.087	1.95	2.20	
D	0.159	0.181	4.05	4.60	
E	0.030	0.063	0.75	1.60	
F	0.075	0.096	1.90	2.45	
G	0.002	0.008	0.05	0.20	
Н	0.077	0.104	1.95	2.65	
К	0.006	0.016	0.15	0.41	

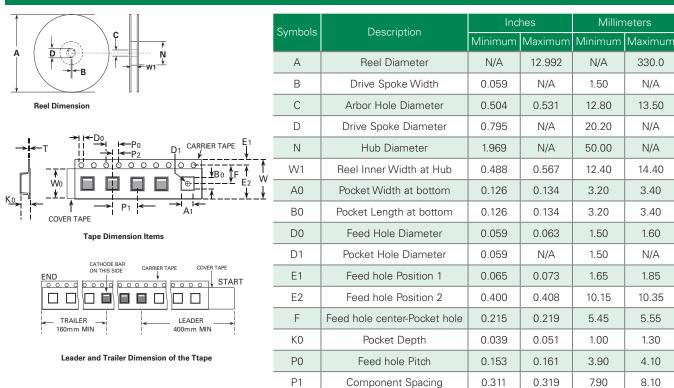
Specifications are subject to change without notice.



Part Numbering System **Part Marking System** DO-214 <u>PLED X 012</u> PLX XXXXX PACKAGE TYPE TYPE PLED: LED Protector Q12: 3.0x3.0mm QFN Cathode Bar to Indicate Diode Direction S: DO-214 V<sub>DRM</sub> 6 Volts QFN 9 Volts **1** PLX 13 Volts xxxx 18 Volts Cathode Bar to Indicate Diode Direction

Packaging							
Package	Description	Packaging Quantity	Industry Standard				
Q12	QFN 3x3	5000	EIA-481-1				
S	DO-214	2500	EIA-481-1				

### Tape and Reel Specification - QFN (3x3)



P2

Т

W

W0

#### ©2011 Littelfuse, Inc.

Specifications are subject to change without notice.

Feed hole center-Pocket hole

Carrier Tape Thickness

Embossed Carrier Tape Width

Cover Tape Width

0.077

0.010

0.453

0.358

0.081

0.014

0.484

0.366

1.90

0.25

11.50

9.10

2.06

0.35

12.30

9.30



## DO-214 Embossed Carrier Reel Pack (RP)

## Meets all EIA-481-1 Standards

